

20V P-Channel Enhancement Mode MOSFET

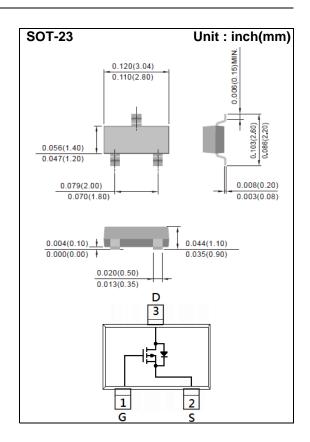
Voltage -20 V Current -4.5A

Features

- RDS(ON) , VGS@-4.5V, ID@-4.5A<46mΩ
- RDS(ON) , VGS@-2.5V, ID@-3.0A<56mΩ
- RDS(ON), VGS@-1.8V, ID@-1.5A<88m Ω
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A5A



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMET	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	-4.5	Α
Pulsed Drain Current		I _{DM}	-18	Α
Power Dissipation	T _a =25°C		1.25	W
	Derate above 25°C	P _D	10	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	100	°C/W
- Junction to Ambient (************************************		3071		C/VV



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D =-250uA		-20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-0.5	-0.74	-1.3	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-4.5A	-	38	46	mΩ	
		V _{GS} =-2.5V, I _D =-3.0A	-	47	56		
		V _{GS} =-1.8V, I _D =-1.5A	-	68	88		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V, V _{GS} =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	Q_g	.,	-	10	-	nC	
Gate-Source Charge	Q_{gs}	V _{DS} =-10V, I _D =-4.5A, V _{GS} =-4.5V (Note 1,2)	-	1.7	-		
Gate-Drain Charge	Q_{gd}	VGS=-4.5V (1000 1,2)	-	2.4	-		
Input Capacitance	Ciss	\/ 40\/ \/ 0\/	-	980	-	pF	
Output Capacitance	Coss	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	100	-		
Reverse Transfer Capacitance	Crss	I=1.UIVIMZ	-	81	-		
Switching							
Turn-On Delay Time	td _(on)	10)/ 1 150	-	9.8	-		
Turn-On Rise Time	tr	V _{DD} =-10V, I _D =-4.5A,	-	54	-	ns	
Turn-Off Delay Time	td _(off)	V _{GS} =-4.5V, R _G =6Ω (Note 1,2)	-	44	-		
Turn-Off Fall Time	tf	RG=012 (1000 1,2)	-	31	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-1.5	Α	
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	-0.78	-1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited



TYPICAL CHARACTERISTIC CURVES

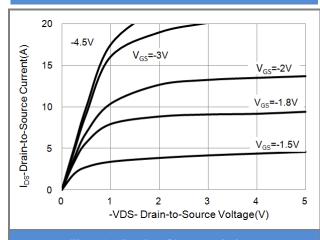


Fig.1 On-Region Characteristics

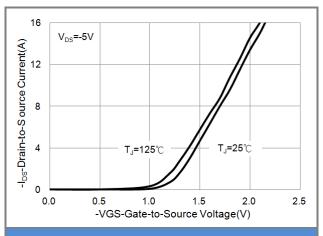


Fig.2 Transfer Characteristics

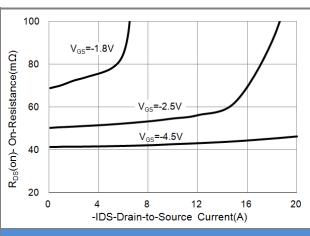


Fig.3 On-Resistance vs. Drain Current

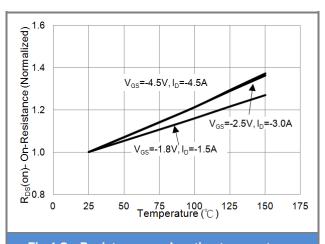
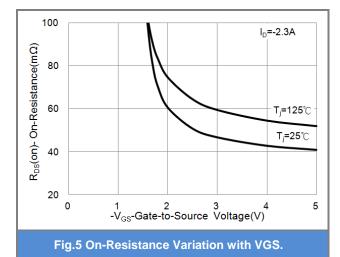
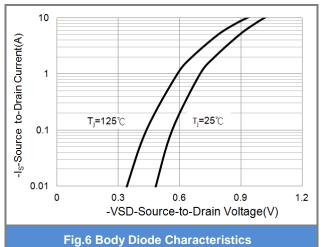


Fig.4 On-Resistance vs. Junction temperature







TYPICAL CHARACTERISTIC CURVES

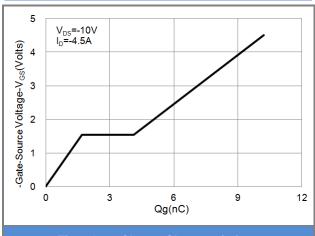


Fig.7 Gate-Charge Characteristics

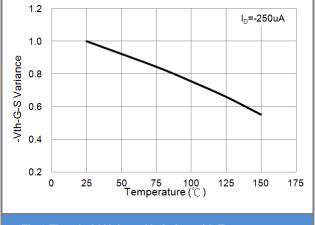


Fig.8 Threshold Voltage Variation with Temperature.

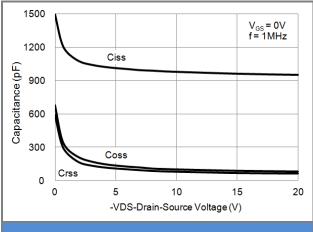


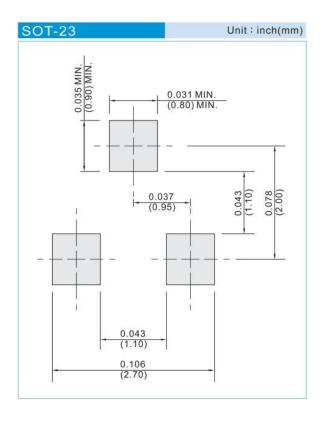
Fig.9 Capacitance vs. Drain-Source Voltage.



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3415A	SOT-23	3K pcs / 7" reel	A5A	
PJA3415A	SOT-23	12K pcs / 13" reel	A5A	

MOUNTING PAD LAYOUT





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